







**AFE4960** ZHCSOJ7A - OCTOBER 2021 - REVISED MARCH 2022

# AFE4960 用于临床可穿戴设备的双通道 ECG、呼吸和起搏脉冲检测模拟前端 (AFE)

## 1 特性

- 支持心电图和呼吸阻抗测量;可配置为 2 通道 ECG 或 1 通道 ECG + 1 通道呼吸
- 可用于符合 IEC 60601-2-47:2012/(R)2016 和 IEC 60601-2-27:2011(R)2016 的系统
- 作为 2 通道 ECG 运行时为 222 μA/通道
- 1个通道上的集成起搏脉冲检测
- 支持 3 导联心电图,可通过并行操作两个或更多 AFE 扩展到 5 导联或更多
- ECG 信号链:
  - 高达 2.048 kHz 的单通道 ECG 采集
  - 高达 1.36 kHz/通道的 2 通道 ECG 采集
  - RLD 输出通过第三电极设置人体偏置
  - INA 增益在 2 至 12 的范围内可进行编程
  - >1 G Ω 输入阻抗, CMRR > 100 dB
  - 输入噪声 (0.5 Hz 至 150 Hz): INA 增益为 3 时为 13 μVpp; INA 增益为 12 时为 5 μ Vpp
  - 集成式 370 Hz 抗混叠低通滤波器
  - 持续导联开/关检测模式
  - 导联阻抗测量模式
- Bio-Z 信号链:
  - 在 30kHz 至 100kHz 的激励频率范围内测量生 物阻抗
  - 正弦波激励或方波激励
  - 呼吸阻抗测量:  $2 k\Omega$  基线阻抗上的  $45 m\Omega$ -pp 噪声
- 双通道 ECG 通道:
  - Bio-Z 接收器,可配置为第 2 个 ECG 通道
- 外部时钟和内部振荡器模式
- 采样深度为 128 的 FIFO, 24 位字
- SPITM, I2C接口:可通过引脚进行选择
- 2.6mm × 2.6mm DSBGA 封装, 0.4mm 间距
- 电源:Rx:1.7V-1.9V, IO:1.7V-1.9V

### 2 应用

- 用于住院和门诊监测的无线贴片
- 用于心律失常检测的事件监视器
- · 手持式 ECG 监护仪
- 便携式多导联 ECG
- 病人生命体征监控:动态心电图、事件、压力和远 程医疗

## 3 说明

AFE4960 可配置为 2 通道 ECG 接收器或 1 通道 ECG 接收器和一个呼吸阻抗通道。AFE 信号链可以灵活地 连接至最多 4 个电极。右腿驱动 (RLD) 放大器输出可 用于设置人体偏置。AFE 具有用于导联开/关检测的直 流引线偏置和用于测量引线阻抗的交流导联偏置。一个 通道支持起搏器脉冲检测。

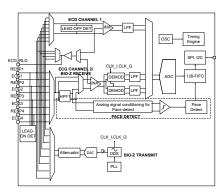
所有信号链输出都由单个 ADC 在明确定义的时隙中转 换,并作为 24 位字存储在 128 样本 FIFO 中,可以使 用 SPI 或 I<sup>2</sup>C 界面读出。

AFE4960 是一种完全集成的解决方案,可实现 3 导联 ECG 系统。两个 AFE 并行的同步操作可用于实现 5 导联 ECG。

### 器件信息

器件型号	封装 <sup>(1)</sup>	封装尺寸(标称值)		
AFE4960	DSBGA (YBG 36)	2.6 mm x 2.6 mm		

如需了解所有可用封装,请参阅数据表末尾的可订购产品附 录。



方框图



# 4 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

### 4.1 Documentation Support

### 4.1.1 Related Documentation

For related documentation, see the following:

- AFE4960 EVM User's Guide, SBAU385
- Analog Front End for 3-Lead and 5-Lead ECG, SBAA536
- 5-Lead ECG Application Report, SBAA523

These documents are available upon request.

## 4.2 接收文档更新通知

要接收文档更新通知,请导航至 ti.com 上的器件产品文件夹。点击*订阅更新* 进行注册,即可每周接收产品信息更改摘要。有关更改的详细信息,请查看任何已修订文档中包含的修订历史记录。

### 4.3 支持资源

TI E2E™ 支持论坛是工程师的重要参考资料,可直接从专家获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题可获得所需的快速设计帮助。

链接的内容由各个贡献者"按原样"提供。这些内容并不构成 TI 技术规范,并且不一定反映 TI 的观点;请参阅 TI 的《使用条款》。

#### 4.4 Trademarks

TI E2E<sup>™</sup> is a trademark of Texas Instruments.

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### 4.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

## 4.6 术语表

TI术语表本术语表列出并解释了术语、首字母缩略词和定义。

## 5 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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### PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
AFE4960YBGR	ACTIVE	DSBGA	YBG	36	3000	RoHS & Green	SAC396	Level-1-260C-UNLIM	-40 to 85	AFE4960	Samples
AFE4960YBGT	ACTIVE	DSBGA	YBG	36	250	RoHS & Green	SAC396	Level-1-260C-UNLIM	-40 to 85	AFE4960	Samples

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

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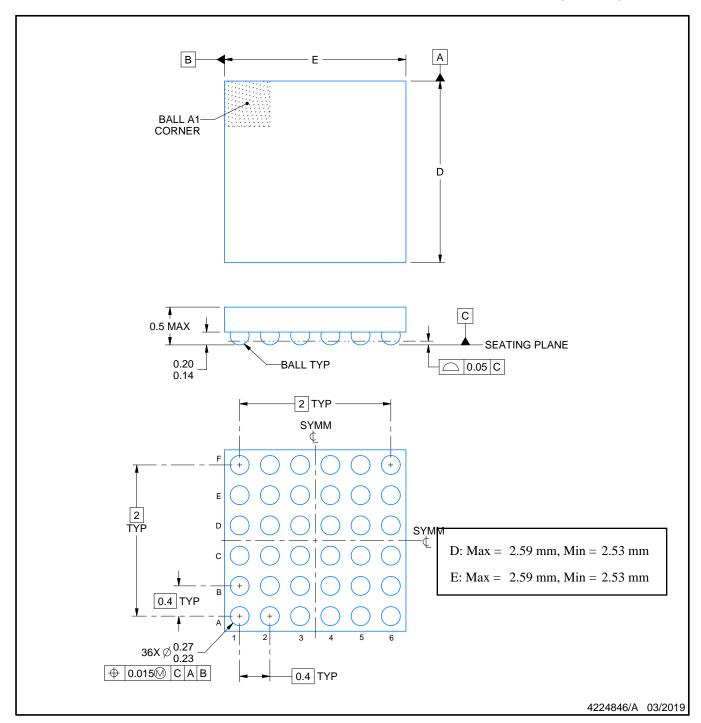


# **PACKAGE OPTION ADDENDUM**

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DIE SIZE BALL GRID ARRAY



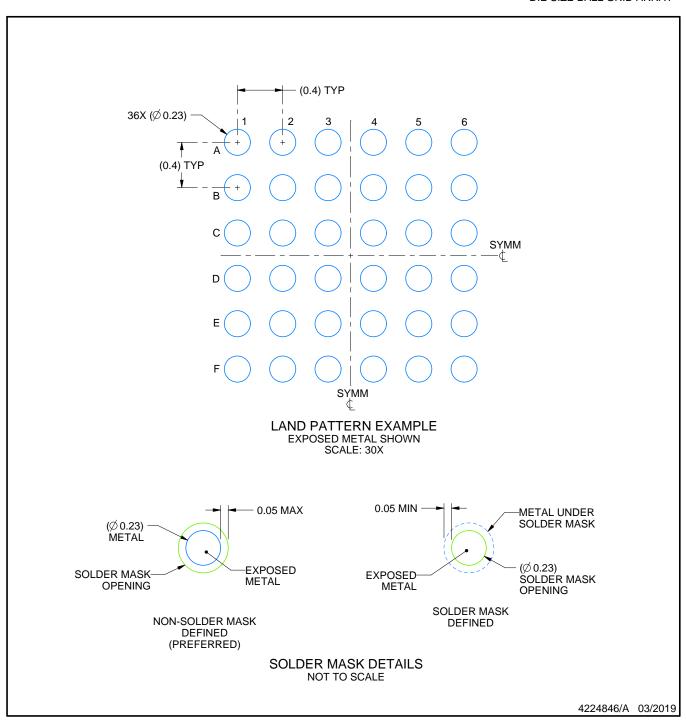
### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.



DIE SIZE BALL GRID ARRAY

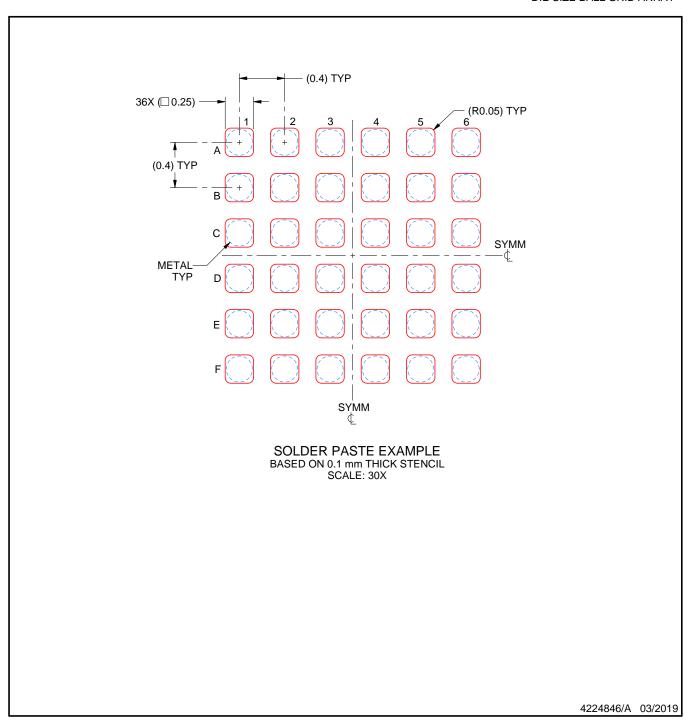


NOTES: (continued)

3. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. See Texas Instruments Literature No. SNVA009 (www.ti.com/lit/snva009).



DIE SIZE BALL GRID ARRAY



### NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.



# 重要声明和免责声明

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